GaAs Dual Gate MES FET

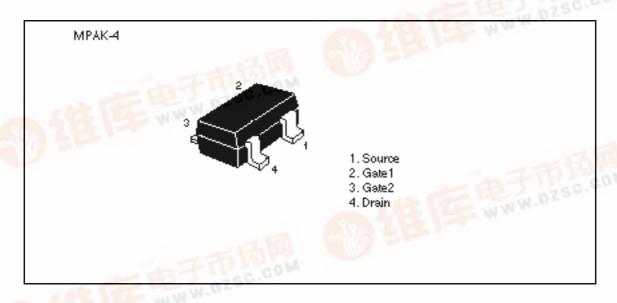
# HITACHI

ADE-208-280 1st. Edition

#### **Application**

UHF TV tuner RF Amplifier

#### Outline





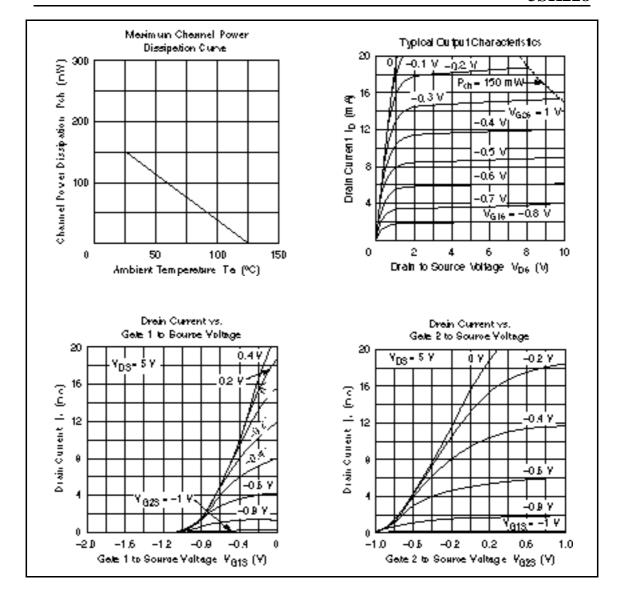
#### **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

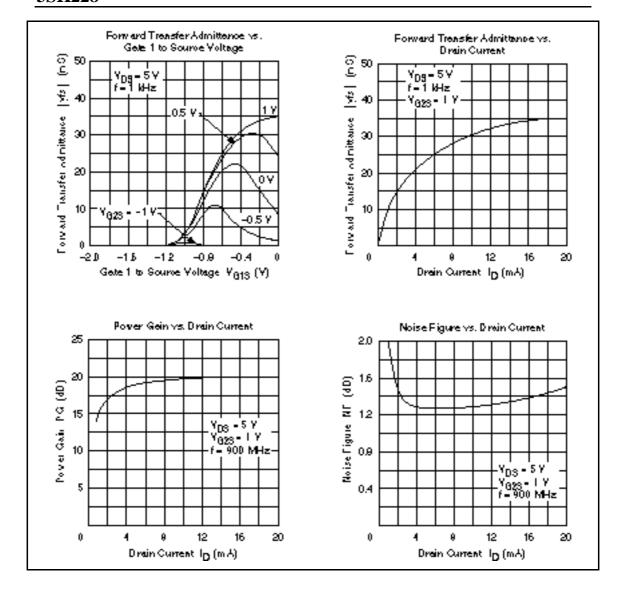
Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DS</sub>	12	V
Gate 1 to source voltage	V <sub>G1S</sub>	-6	V
Gate 2 to source voltage	$V_{\sf G2S}$	-6	V
Drain current	I <sub>D</sub>	50	mA
Channel power dissipation	Pch	150	mW
Channel temperature	Tch	125	°C
Storage temperature	Tstg	-55 to +125	°C

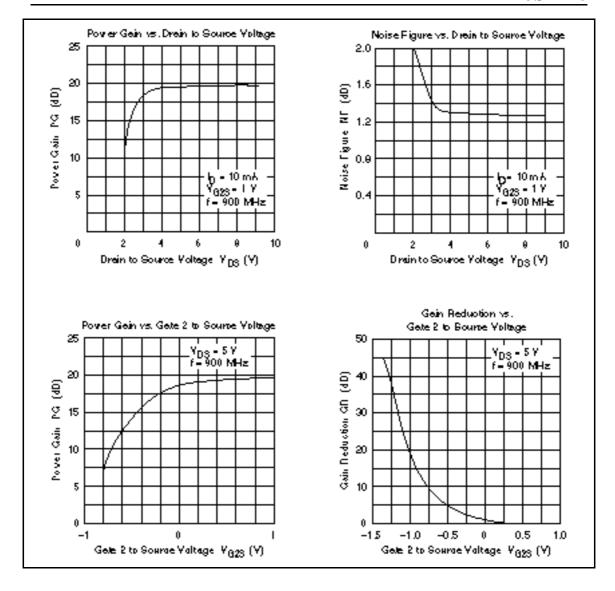
#### **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source cutoff current	I <sub>DSX</sub>	_	_	50	μA	$V_{DS} = 12 \text{ V}, V_{G1S} = -3 \text{ V}, V_{G2S} = 0$
Gate 1 to source breakdown voltage	$V_{(BR)G1SS}$	-6	_	_	V	$I_{G1} = -10 \ \mu A, \ V_{G2S} = V_{DS} = 0$
Gate 2 to source breakdown voltage	$V_{(BR)G2SS}$	-6	_	_	V	$I_{G2} = -10 \mu A, V_{G1S} = V_{DS} = 0$
Gate 1 cutoff current	$I_{\rm G1SS}$	_	_	<b>-</b> 5	μΑ	$V_{G1S} = -5 \text{ V}, V_{G2S} = V_{DS} = 0$
Gate 2 cutoff current	I <sub>G2SS</sub>	_	_	<b>-</b> 5	μΑ	$V_{G2S} = -5 \text{ V}, V_{G1S} = V_{DS} = 0$
Drain current	I <sub>DSS</sub>	10	17	32	mA	$V_{DS} = 5 \text{ V}, V_{G1S} = V_{G2S} = 0$
Gate 1 to source cutoff voltage	$V_{\text{G1S(off)}}$	_	-1.1	-1.5	V	$V_{DS} = 5 \text{ V}, V_{G2S} = 0,$ $I_{D} = 100  \mu\text{A}$
Gate 2 to source cutoff voltage	$V_{\text{G2S(off)}}$	_	-1.1	-1.5	V	$V_{DS} = 5 \text{ V}, V_{G1S} = 0,$ $I_{D} = 100  \mu\text{A}$
Forward transfer admittance	y <sub>fs</sub>	20	34	_	mS	$V_{DS} = 5 \text{ V}, V_{G2S} = 1 \text{ V},$ $I_{D} = 10 \text{ mA}, f = 1 \text{ kHz}$
Input capacitance	Ciss	_	0.58	1.0	pF	$V_{DS} = 5 \text{ V}, V_{G1S} = V_{G2S} = -3 \text{ V},$ f = 1 MHz
Output capacitance	Coss	_	0.36	0.6	pF	_
Reverse transfer capacitance	Crss	_	0.028	0.05	pF	_
Power gain	PG	17	19.6	_	dB	$V_{DS} = 5 \text{ V}, V_{G2S} = 1 \text{ V},$ $I_{D} = 10 \text{ mA}, f = 900 \text{ MHz}$
Noise figure	NF	_	1.3	2.0	dB	

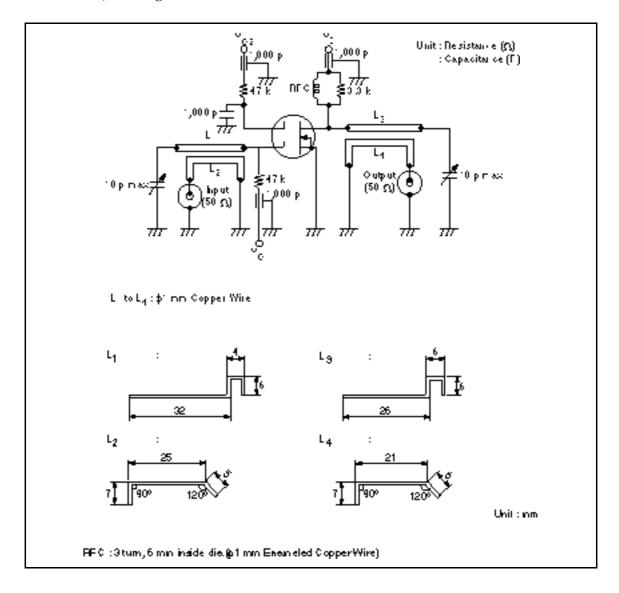
Note: Marking is "XR-".







#### Power Gain, Noise Figure Test Circuit



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